INTEGRATED CIRCUIT TOSHIBA TECHNICAL DATA

8CH DARLINGTON SINK DRIVER

The TD62081AP/CP/F/AF Series are high-voltage, high-current darlington drivers comprised of eight NPN darlington pairs.

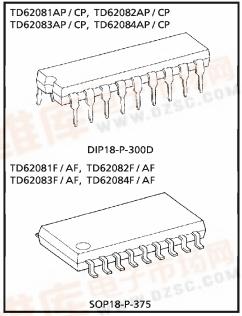
All units feature integral clamp diodes for switching inductive loads.

Applications include relay, hammer, lamp and display (LED) drivers.

FEATURES

- Output current (single output)
 500mA (Max.) (TD62081AP/F/AF series)
 400mA (Max.) (TD62081CP series)
- High sustaining voltage output
 35V (Min.) (TD62081F series)
 50V (Min.) (TD62081AP / AF series)
 100V (Min.) (TD62081CP series)
- Output clamp diodes
- Inputs compatible with various types of logic.

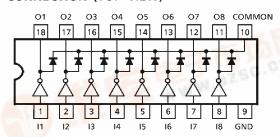
Package type-AP, CP: DIP-18pinPackage type-F, AF: SOP-18pin



Weight DIP18-P-300D : 1.478g (Typ.) SOP18-P-375 : 0.41g (Typ.)

TYPE	INPUT BASE RESISTOR	DESIGNATION
TD62081AP/CP/F/AF	External	General Purpose
TD62082AP/CP/F/AF	10.5-k Ω + 7V Zenner diode	14~25V PMOS
TD62083AP/CP/F/AF	2.7kΩ	TTL, 5V CMOS
TD62084AP/CP/F/AF	10.5k Ω	6~15V PMOS, CMOS

PIN CONNECTION (TOP VIEW)



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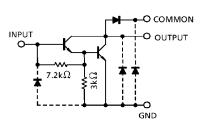
INTEGRATED CIRCUIT **TOSHIBA**

TECHNICAL DATA

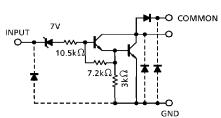
TD62081AP, TD62081CP, TD62081F, TD62081AF TD62082AP, TD62082CP, TD62082F, TD62082AF TD62083AP, TD62083CP, TD62083F, TD62084AP, TD62084CP, TD62084F, TD62084AF

SCHEMATICS (EACH DRIVER)

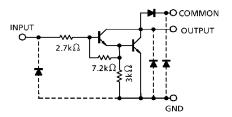
TD62081AP/CP/F/AF



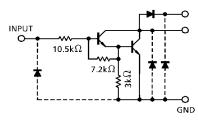
TD62082AP/CP/F/AF



TD62083AP/CP/F/AF



TD62084AP/CP/F/AF



(Note) The input and output parasitic diodes cannot be used as clamp diodes.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Output Custaining	AP, AF		-0.5~50	V	
Output Sustaining Voltage	СР	VCE (SUS)	- 0.5~100		
Voltage	F		-0.5~35		
Output Current		1	500	m A / ch	
Output Current	СР	IOUT	400	mA / ch	
Input Voltage		V _{IN} (Note 1)	-0.5~30	V	
Input Current		I _{IN} (Note 2)	25	mA	
Clamp Diode Reverse	AP, AF		50		
Voltage	CP	∣ ∨ _R	100	V	
Voltage	F		35		
Clamp Diode Forward		1-	500	mA	
Current	СР	ΙF	400	IIIA	
Power Dissipation	AP, CP	D-	1.47	10/	
Power Dissipation	F, AF	PD	0.96	W	
Operating Temperature	е	T _{opr}	-40∼8 5	°C	
Storage Temperature		T _{stg}	- 55∼150	°C	

(Note 1) Except TD62081AP/CP/F/AF

(Note 2) Only TD62081AP/CP/F/AF

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INTEGRATED CIRCUIT **TOSHIBA**

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TECHNICAL DATA

TD62081AP, TD62081CP, TD62081F, TD62081AF TD62082AP, TD62082CP, TD62082F, TD62082AF TD62083AP, TD62083CP, TD62083F, TD62084AP, TD62084CP, TD62084F, TD62084AF

RECOMMENDED OPERATING CONDITIONS ($Ta = -40 \sim 85$ °C)

CHARACTI	ERISTIC	-	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
I/)uthuit Suctaining L		AP, AF			0	_	50	
Voltage	y	CP	VCE (SUS)		0		100	V
voitage		F			0	_	35	
		AP, CP		T _{pw} = 25ms, Duty = 10%, 8 Circuits	0	_	347	
Output Current		Ar, Cr	lau -	T _{pw} = 25ms, Duty = 50%, 8 Circuits	0	_	123	mA / ch
Output Current		F, AF	IOUT	T _{pw} = 25ms, Duty = 10%, 8 Circuits	0	_	268	ma/cm
				T _{pw} = 25ms, Duty = 50%, 8 Circuits	0	_	90	
Input Voltage	Excep TD62 CP/F	081AP/	VIN		0	_	30	V
	TD620 CP/F				14	_	30	
(Output On) CP/F TD62 CP/F	TD62 CP/F	083AP / / AF	V _{IN} (ON)		3.5	_	30	v
	084AP / / AF			8	_	30		
Input Current	Only TD62 CP/F	081AP / / AF	IIN		0	_	5	mA
		AP, AF			_	_	50	
Clamp Diode Rev	rerse	СР	v_{R}		_	_	100	V
Voltage		F			_	_	35	
Clamp Diode For	ward		1-		_	_	400	
Current		СР	ΙF		_	_	320	mA
Power Dissipation	n	AP, CP F, AF	PD		_ 	_	0.52	w

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INTEGRATED CIRCUIT TOSHIBA TECHNICAL DATA

TD62081AP, TD62081CP, TD62081F, TD62081AF TD62082AP, TD62082CP, TD62082F, TD62082AF TD62083AP, TD62083CP, TD62083F, TD62084AP, TD62084CP, TD62084F, TD62084AF

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

СНАР	RACTERISTI	-	SYMBOL	TEST CIR- CUIT	TEST COND	ITION	MIN.	TYP.	MAX.	UNIT	
		AP, AF			V _{CE} = 50V				50		
		СР			V _{CE} = 100V	Ta = 25°C	_				
		F			V _{CE} = 35V						
		AP, AF			V _{CE} = 50V						
		СР			V _{CE} = 100V	Ta = 85°C	_	_	100		
Output Leak	age	F	1 .	,	V _{CE} = 35V	1					
Current		AP, AF	ICEX	1	V _{CE} = 50V					μ A	
	TD6208	2 CP			V _{CE} = 100V	$V_{IN} = 6V$	_	_	500		
		F			V _{CE} = 35V						
		AP, AF			V _{CE} = 50V						
	TD6208	1 CP			V _{CE} = 100V	$V_{IN} = 1V$	_	_	500		
		F			V _{CE} = 35V						
Callantas Fosi	44 a.u. Ca4a	·:			I _{OUT} = 350mA, I _I	N = 500μA		1.3	1.6		
Collector-Emi	tter Satura	tion	VCE (sat)	2	I _{OUT} = 200mA, I _I	N = 350μA	_	1.1	1.3	V	
Voltage					I _{OUT} = 100mA, I _I	$N = 250 \mu A$		0.9	1.1		
TD620 CP/F/		2082AP/ F/AF			V _{IN} = 17V			0.82	1.25		
Input		2083AP / F / AF	IIN (ON)	2	V _{IN} = 3.85V V _{IN} = 5V		_	0.93	1.35	mA	
Current	-	2084AP /					_	0.35	0.5		
	CP/	F/AF			V _{IN} = 12V		_	1.0	1.45		
			IN (OFF)	4	l _{OUT} = 500μA, Τα	a = 85°C	50	65	_	μΑ	
TD620 CP / F /		2082AP/ F/AF	111 (011)	·	V _{CE} = 2V, I _{OUT} =			_	13	,	
	TDC	2002 4 D /			V _{CE} = 2V, I _{OUT} =	200mA	_	_	2.4		
		2083AP/			V _{CE} = 2V, I _{OUT} =		_	_	2.7		
Input Voltage	e CP/	F/AF	VIN (ON)	5	V _{CE} = 2V, I _{OUT} =		_	_	3.0	V	
(Output On)			(5,		V _{CE} = 2V, I _{OUT} =	125mA		_	5.0		
	TD6	2084AP/			V _{CE} = 2V, I _{OUT} =		_	_	6.0		
	CP/	F/AF			V _{CE} = 2V, I _{OUT} =	275mA	_	_	7.0		
					V _{CE} = 2V, I _{OUT} =	350mA	_	_	8.0	7	
DC Current T	ransfer Ra	io	hFE	2	V _{CE} = 2V, I _{OUT} =	350mA	1000	_	_		
Clamp Diada	Poverse C	irront	1_	6	Ta = 25°C (Note)		_	_	50		
Clamp Diode	Reverse C	urrent	IR	6	Ta = 85°C (Note)		_	_	100	00 μA	
Clamp Diode	Forward		V-	7	I _F = 350mA		_	_	2.0	V	
Voltage		СР	- V _F	7	I _F = 280mA			_	1.8		
Input Capacit	tance		CIN				_	15		рF	

(Note) $V_R = V_R MAX$.

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INTEGRATED CIRCUIT TOSHIBA

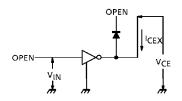
TECHNICAL DATA

TD62081AP, TD62081CP, TD62081F, TD62081AF TD62082AP, TD62082CP, TD62082F, TD62082AF TD62083AP, TD62083CP, TD62083F, TD62084AP, TD62084CP, TD62084F, TD62084AF

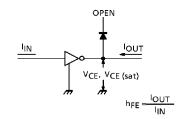
CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	AP, AF			$R_L = 125\Omega$, $V_{OUT} = 50V$	_	0.1		
Turn-On Delay	CP	tON		$R_L = 312\Omega$, $V_{OUT} = 100V$	_	0.1	_	
F	F		8	$R_L = 87.5\Omega$, $V_{OUT} = 35V$	_	0.1	_	
	AP, AF		0	$R_L = 125\Omega$, $V_{OUT} = 50V$	_	0.2	_	μ s
Turn-Off Delay	СР	tOFF		$R_L = 312\Omega$, $V_{OUT} = 100V$	_	3.0		
	F			$R_L = 87.5\Omega$, $V_{OUT} = 35V$	_	0.2	_	

TEST CIRCUIT

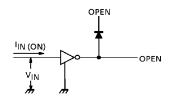
1. ICEX



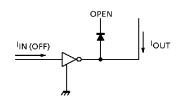
2. VCE (sat), hFE



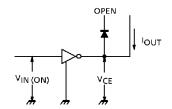
3. IIN (ON)



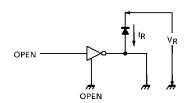
4. IN (OFF)



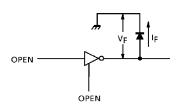
5. V_{IN} (ON)



6. I_R



7. V_F



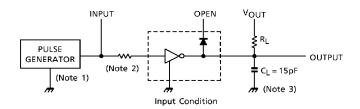
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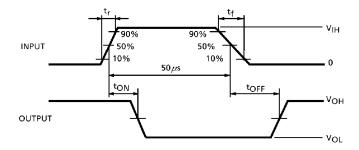
INTEGRATED CIRCUIT **TOSHIBA**

TECHNICAL DATA

TD62081AP, TD62081CP, TD62081F, TD62081AF TD62082AP, TD62082CP, TD62082F, TD62082AF TD62083AP, TD62083CP, TD62083F, TD62084AP, TD62084CP, TD62084F, TD62084AF

8. ton, toff





- (Note 1) Pulse Width $50\mu s$, Duty Cycle 10%Output Impedance 50Ω , $t_r \le 5ns$, $t_f \le 10ns$
- (Note 2) See below.

as of the same

INPUT CONDITION

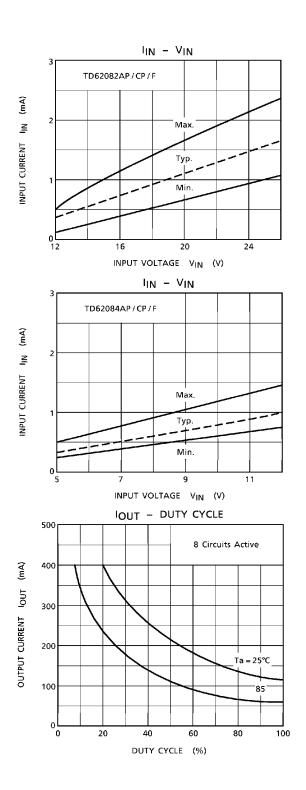
TYPE NUMBER	R1	V _{IH}
TD62081AP/CP/F/AF	2.7k Ω	3V
TD62082AP/CP/F/AF	0Ω	13V
TD62083AP/CP/F/AF	0Ω	3V
TD62084AP/CP/F/AF	0Ω	8V

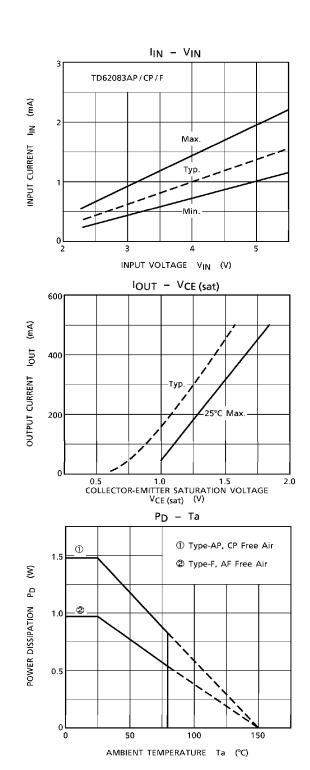
(Note 3) C_L includes probe and jig capacitance

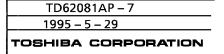
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INTEGRATED CIRCUIT TOSHIBA TECHNICAL DATA

TD62081AP, TD62081CP, TD62081F, TD62081AF TD62082AP, TD62082CP, TD62082F, TD62082AF TD62083AP, TD62083CP, TD62083F, TD62084AP, TD62084CP, TD62084F, TD62084AF









INTEGRATED CIRCUIT **TOSHIBA**

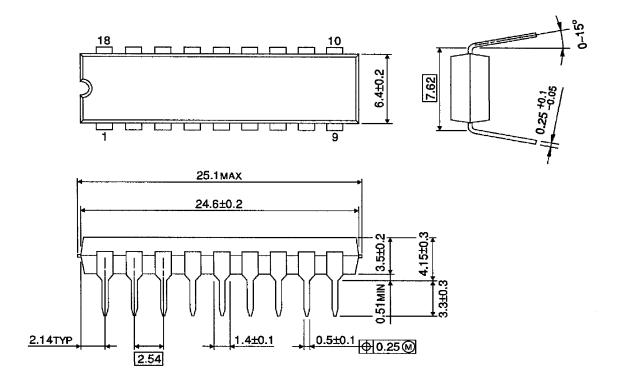
TECHNICAL DATA

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OUTLINE DRAWING

DIP18-P-300D

Unit: mm



Weight: 1.478g (Typ.)

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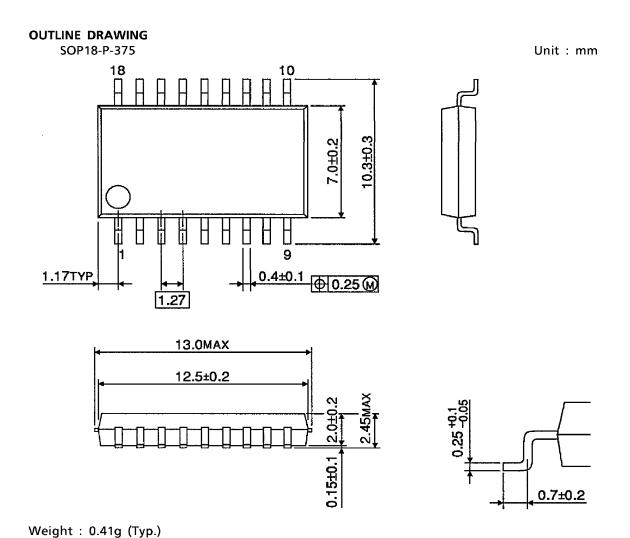


INTEGRATED CIRCUIT **TOSHIBA**

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TECHNICAL DATA

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TD62	081	AP - 9*	
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